

## 74HCT126

#### **QUADRUPLE 3-STATE BUFFERS OE HIGH**

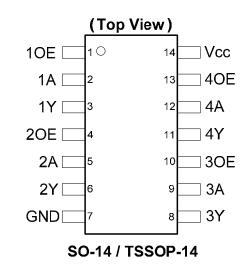
### Description

The 74HCT126 provides provides four independent buffer gates with 3-state outputs. Each buffer has a separate enable pin that if driven with a low logic level places the corresponding output in the high impedance state. The device is designed for operation with a power supply range of 4.5V to 5.5V.

## Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Pin Compatible with Low Power Schottky (LSTTL)
- Inputs Are TTL Voltage Level Compatible
- Sinks or sources 4mA at  $V_{CC} = 4.5V$
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
  - 200-V Machine Model (A115-A)
  - 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## Pin Assignments



## Applications

- General Purpose Logic
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box

#### Notes:

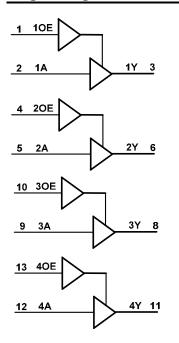
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  - 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



# **Pin Descriptions**

Pin Number	Pin Name	Description
1	10E	Data Enable Input (active high)
2	1A	Data Input
3	1Y	Data Output
4	20E	Data Enable Input (active high)
5	2A	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	ЗA	Data Input
10	30E	Data Enable Input (active high)
11	4Y	Data Output
12	4A	Data Input
13	40E	Data Enable Input (active high)
14	Vcc	Supply Voltage

# Logic Diagram



# **Function Table**

Inp	Output	
OE	Α	Y
Н	Н	Н
Н	L	L
L	Х	Z



## Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range (Note 5)	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current $V_{I} < -0.5V$ or Vi > $V_{CC} + 0.5V$	±20	mA
loк	Output Clamp Current $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$	±20	mA
I <sub>O</sub>	Continuous Output Current -0.5V < Vo V <sub>CC</sub> +0.5V	+/-25	mA
Icc	Continuous Current Through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

5. Input Voltage cannot exceed  $V_{CC}$  to the extent the Maximum clamp current is exceeded.

# Recommended Operating Conditions (Note 6) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		4.5	5.5	V
VI	Input Voltage		0	V <sub>CC</sub>	V
Vo	Output Voltage		0	V <sub>CC</sub>	V
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 4.5V$ to 5.5V		500	ns/V
T <sub>A</sub>	Operating Free-Air Temperature		-40	+125	°C

Note: 6. Unused inputs should be held at  $V_{CC}$  or Ground.

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symphol	Deremeter	Test Conditions	Ň	T <sub>A</sub> = -40°	C to +85°C	T <sub>A</sub> = -40°C	to +125°C	Unit
Symbol	Parameter	rest conditions	V <sub>cc</sub>	Min	Max	Min	Max	Unit
VIH	High-level Input Voltage		4.5V to 5.5V	2.0		2.0		V
VIL	Low-level Input Voltage		4.5V to 5.5V		0.8		0.8	V
M	$V_{OH}  \begin{array}{l} \text{High-level Output} \\ \text{Voltage} \end{array}  \begin{array}{l} I_{OH} = -20 \mu \text{A} & \begin{array}{c} 4.5 \text{V} \\ \hline I_{OH} = -4 \text{mA} & \begin{array}{c} 4.5 \text{V} \end{array} \end{array}$	4.4		4.4		V		
VOH		I <sub>OH</sub> = -4mA	4.5V	3.84		3.70		v
N/	Low-level Output	I <sub>OL</sub> = 20μΑ	4.5V		0.1		0.1	V
Vol	Voltage	I <sub>OL</sub> = 4.0mA	4.5V		0.33		0.4	v
l <sub>oz</sub>	Z State Leakage Current	$V_{\rm O}$ = 0 to 5.5V	5.5V		± 5.0		± 10	μA
I <sub>I</sub>	Input Current	$V_1 = GND$ to 6.0V	6.0V		± 1		± 1	μA
I <sub>CC</sub>	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	6.0V		20		40	μA
ΔI <sub>CC</sub>	Additional Supply Current	One Input at $V_{CC}$ -2.1V Other Pins at $V_{CC}$ or GND	4.5V to 5.5V		675		735	μA



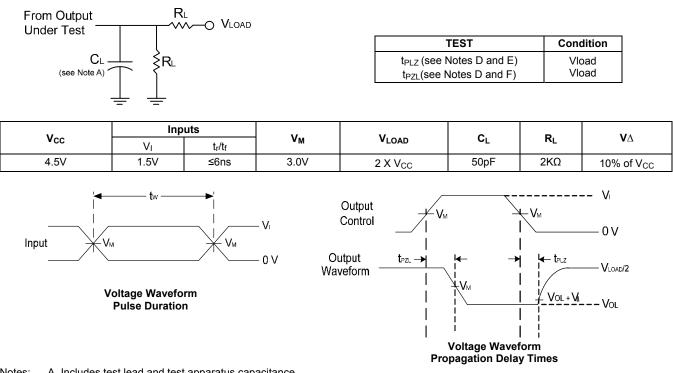
## **Switching Characteristics**

Symbol	vmbol Parameter Test Conditions		ditiona Var		Γ <sub>A</sub> = +25°0	:	-40°C to +85°C	-40°C to +125°C	Unit												
Symbol	Falametei	Test Conditions	Vcc	Min	Тур	Max	Max	Max	Unit												
<b>t</b>	Propagation				15	25	31	38	ns												
t <sub>PD</sub>	Delay $A_N$ to $Y_N$	Figure 1 4.5 C <sub>L</sub> = 50pF 4.5			_	15	25	51	50	115											
1	Enable Time				15	28	35	42	20												
t <sub>EN</sub>	$OE_N$ to $Y_N$		-	-	-	-	-	-	-	-	-	-	-	- 4.5V	4.5V		15	20	55	42	ns
	DisableTime					15	25	31	38	20											
t <sub>DIS</sub>	$OE_N$ to $Y_N$			_		_	15	25	51	30	ns										
t <sub>t</sub>	Transition Time			_	5	12	15	18	ns												

## Operating Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V <sub>CC</sub> = 5.5V Typ	Unit
C <sub>pd</sub>	Power dissipation capacitance per gate	f = 1MHz	24	pF
Cl	Input Capacitance	$V_I = V_{CC} - or GND$	3.5	pF

## **Parameter Measurement Information**



A. Includes test lead and test apparatus capacitance. Notes:

B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.

C. The inputs are measured one at a time with one transition per measurement.

D. For the open drain device tPLZ and tPZL are the same as tPD.

E.  $t_{\text{PZL}}$  is measured at V<sub>M</sub>.

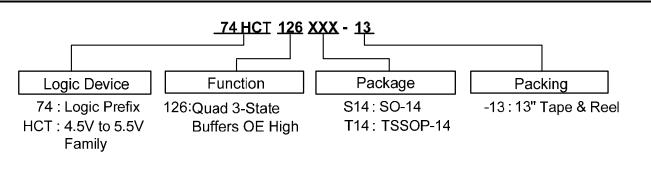
D.  $t_{PLZ}\,$  is measured at V\_OL +V\_{\Delta.}

F. A Thevenin equivalent load may be used in place of  $V_{\text{CC}}$  X 2 and resistor divider.

#### Figure 1 Load Circuit and Voltage Waveforms



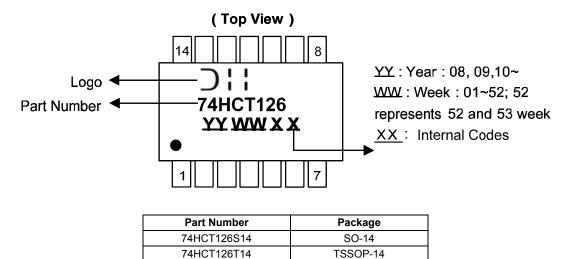
# **Ordering Information**



	Device	Package Code	Packaging	7" Tape a	and Reel
	Device	Fackage Coue	Fackaging	Quantity	Part Number Suffix
Pb.	74HCT126S14-13	S14	SO-14	2500/Tape & Reel	-13
PD.	74HCT126T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

# **Marking Information**

#### (1) SO-14, TSSOP-14

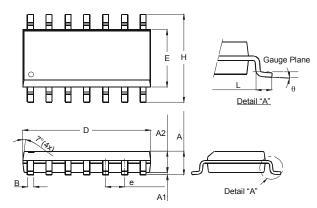




## Package Outline Dimensions (All dimensions in mm.)

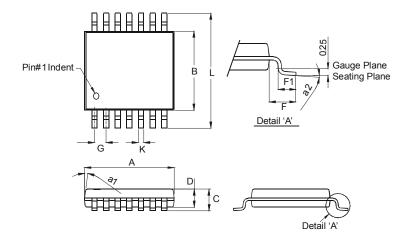
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

#### Package Type: SO-14



	SO-14	
Dim	Min	Max
Α	1.47	1.73
A1	0.10	0.25
A2	1.45	Тур
В	0.33	0.51
D	8.53	8.74
Е	3.80	3.99
е	1.27	Тур
Н	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Di	mensions	s in mm

Package Type: TSSOP-14



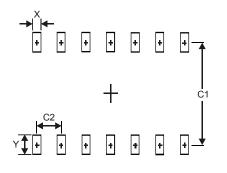
	TSSOP-14				
Dim	Min	Max			
a1	7° (	4X)			
a2	0°	8°			
Α	4.9	5.10			
В	4.30	4.50			
С		1.2			
D	0.8	1.05			
F	1.00	Тур			
F1	0.45	0.75			
G	0.65	Тур			
Κ	0.19	0.30			
Ĺ	6.40	Тур			
All Dir	nensions	s in mm			



## **Suggested Pad Layout**

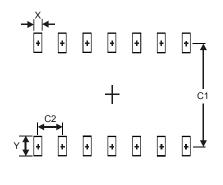
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

#### Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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